Diode Semiconductor Device - Page 1 of 1



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	Material
Inclosure	material:

Glass

**Overall Length:** 

0.300 inches

# **Terminal Length:**

1.000 inches

## **Overall Diameter:**

0.130 inches

**Function For Which Designed:** 

Voltage regulator

#### **Mounting Method:**

Terminal

#### Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

12.0 regulator voltage

### **Current Rating Per Characteristic:**

32.00 milliamperes repetitive peak forward current

### **Power Rating Per Characteristic:**

400.0 milliwatts small-signal input power, common-collector preset

### Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

### **Special Features:**

Hnuclear hardness critical item; no drawing to determine if isc code 1 item should also be nuclear hardness. Can't change criticality code to reflect nuclear hardness; junction pattern arrangement: pin

### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

### **Terminal Type And Quantity:**

2 uninsulated wire lead

#### **Specification Data:**

81349-mil-s-19500/435 government specification

#### Shelf Life:

N/a

# Unit Of Measure:

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# Demilitarization:

No

# Fiig:

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